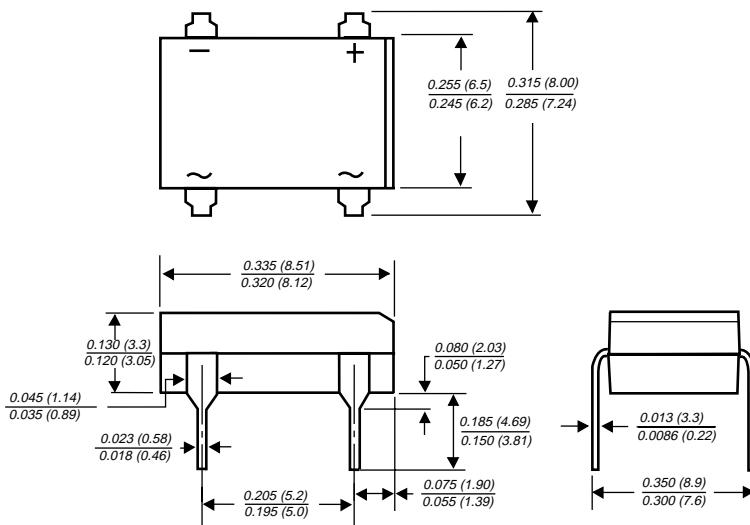



**Case Style DFM**


## Miniature Glass Passivated Ultrafast Bridge Rectifier

 Reverse Voltage 50 and 200V  
 Forward Current 1.0A

### Features

- Plastic package used has Underwriters Laboratory Flammability Classification 94V-0
- This series is UL listed under Recognized Component Index, file number E54214
- Glass passivated chip junction
- High forward surge current capability
- Ideal for printed circuit boards
- Superfast recovery times for high efficiency
- High temperature soldering guaranteed: 260°C/10 seconds, at 5 lbs. (2.3kg) tension

### Mechanical Data

**Case:** Molded plastic body over passivated junctions

**Terminals:** Plated leads solderable per MIL-STD-750, Method 2026

**Polarity:** Polarity symbols as marked on body

**Mounting Position:** Any

**Weight:** 0.014 oz., 0.4 g

**Packaging codes/options:**

45/50 ea. per Bulk Tube

## Maximum Ratings & Thermal Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	EDF1AM	EDF1BM	EDF1CM	EDF1DM	Unit
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	106	140	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	150	200	V
Maximum average forward output rectified current at T <sub>A</sub> = 40°C	I <sub>F(AV)</sub>			1.0		A
Peak forward surge current single half sine-wave superimposed on rated load (JEDEC Method) T <sub>J</sub> = 150°C	I <sub>FSM</sub>			50		A
Rating for fusing (t < 8.3ms)	I <sup>2</sup> t		10			A <sup>2</sup> sec
Typical thermal resistance per leg (Note 1)	R <sub>θJA</sub> R <sub>θJL</sub>		38			°C/W
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>		-55 to +150			°C

## Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	EDF1AM	EDF1BM	EDF1CM	EDF1DM	Unit
Max. instantaneous forward voltage drop per leg at 1.0A	V <sub>F</sub>		1.05			V
Maximum reverse current	I <sub>R</sub>		5.0			µA
at rated DC blocking voltage			1.0			mA
Maximum reverse recovery time at I <sub>F</sub> = 0.5A, I <sub>R</sub> = 1.0A, I <sub>rr</sub> = 0.25A	t <sub>rr</sub>		50			ns

Note: (1) Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.51 x 0.51" (13 x 13mm) copper pads

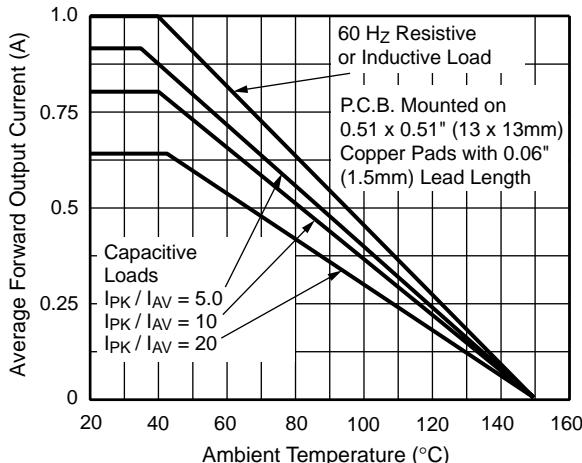
# EDF1AM thru EDF1DM



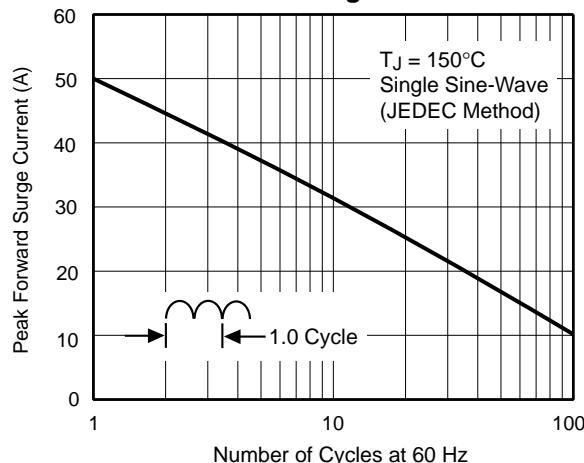
Vishay Semiconductors  
formerly General Semiconductor

## Ratings and Characteristic Curves ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

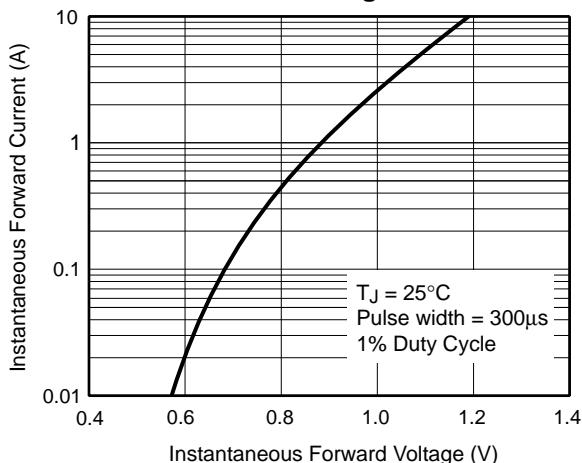
**Fig. 1 - Derating Curves Output Rectified Current**



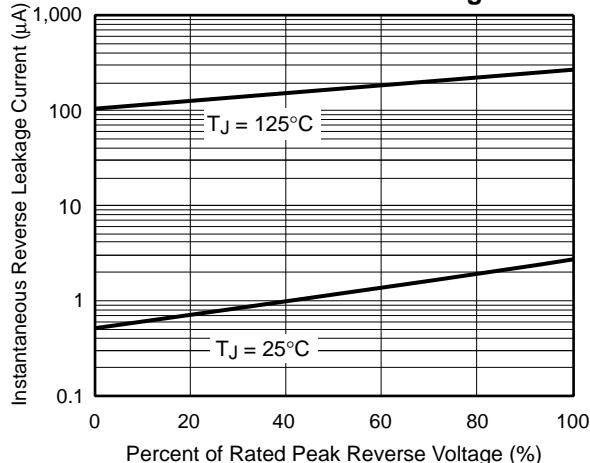
**Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current**



**Fig. 3 - Typical Forward Characteristics Per Leg**



**Fig. 4 - Typical Reverse Leakage Characteristics Per Leg**



**Fig. 5 - Typical Junction Capacitance Per Leg**

